

Switching characteristics of diode

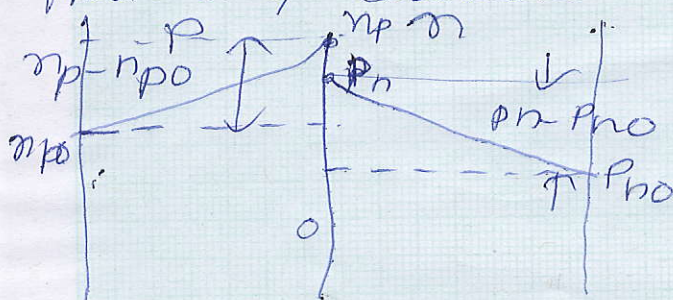
⑦

When diode is switched from forward bias to the reverse biased state or vice versa, it takes finite time to attain a steady state.

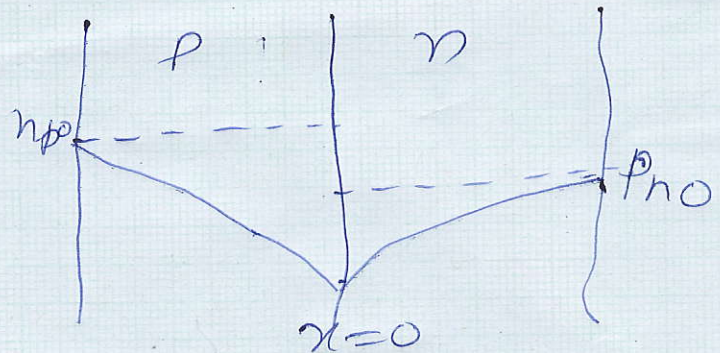
This time consists of a transient and an interval of time before the diode attains a steady state. The behaviour of the diode during this time is called switching characteristics of diode.

Forward biased junction:

Large number of electrons diffuse from n side to p side and large number of holes diffuse from p side to n side. On each side there is a large no. of minority carriers.



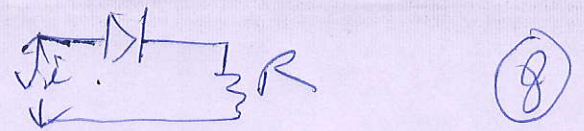
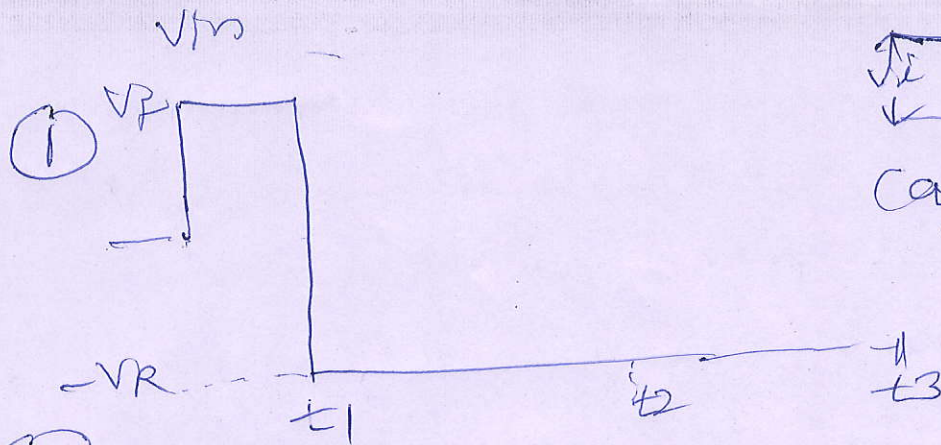
(a) Forward bias



(b) Reverse bias

Fig: Distribution of minority carrier distribution

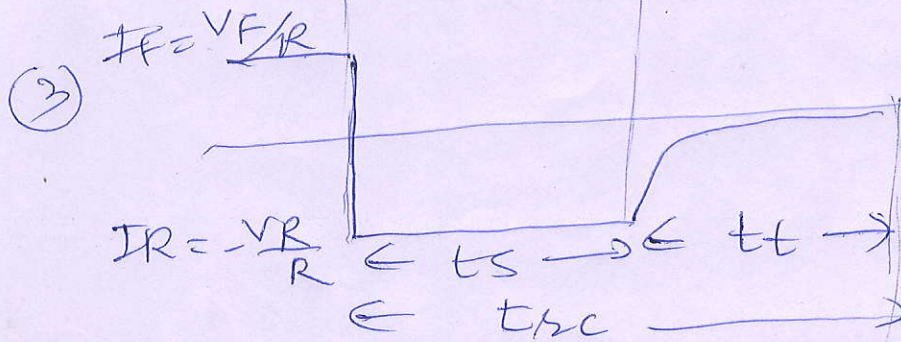
When diode is switched from forward to reverse bias, $p_n - p_{n0}$ & $n_p - n_{p0}$ reduces to zero. Till that time diode continues to conduct.



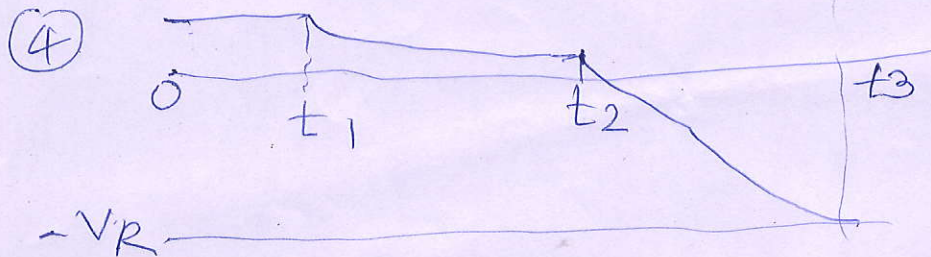
(a) Input voltage



(b) Minority carrier concentration



(c) Diode current



Diode voltage

① Input voltage:

Till time t_1 , the forward voltage applied is V_F , and the diode is forward biased. Resistance " R " is large enough such that drop across diode, is very small compared to drop across " R ".

$$I_F \approx \frac{V_F}{R} \text{ neglecting forward resistance of diode}$$

② Minority carrier concentration

At time " t_1 ", the applied voltage is suddenly reversed and $-V_R$ is applied to the circuit.

Diode does not switch immediately. The no. of minority carriers take time to reduce from $P_n - P_{n0}$ to zero at the junction. Due to this at t_1 current just reverses and remains at that reversed value $-I_R$ till the minority carrier concentration reduces to zero.

The current is given by $-I_R = -\frac{V_R}{R}$. This continues to flow till time t_2 .

$t_s = t_1 \text{ to } t_2 =$ storage time as minority charge carriers remain stored and decrease slowly to zero.

(3) From t_2 onwards the diode voltage starts to reverse and the diode current starts decreasing.

At $t = t_3$, the diode state completely gets reversed and attains steady state in reverse biased condition.

$t_t = t_2 \text{ to } t_3 =$ time required by the diode current to reduce to its reverse saturation value is called transition interval or transition time.

$t_{rr} = t_s + t_t =$ reverse recovery time.

It ranges from a few μ secs to μ sec. Specially manufactured diodes can have

$t_{rr} =$ few p secs.

t_{rr} limits the max. operating freq. of the diode.

$$T = 10 \text{ } \mu\text{s}$$

$$\text{i.e. } f_{\text{max}} = \frac{1}{T} = \frac{1}{10 \text{ } \mu\text{s}}$$

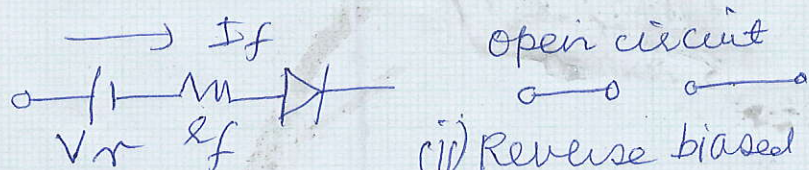
(10)

Forward recovery time: is the time difference between the 10% point of the diode voltage and the time when this voltage reaches and remains with 10% of its final value t_{fr} does not cause serious problem.

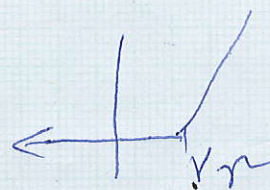
CIRCUIT MODELS OF A DIODE

The diode is required to be replaced by the equivalent circuit in many practical electronic circuits for the analysis purpose. Such an equivalent circuit of a diode is called circuit model.

(i) PRACTICAL DIODE MODEL



(ii) Reverse biased



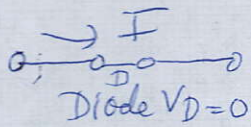
V-I characteristics

(i) Forward Biased

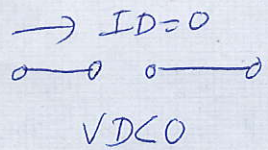
(i) Forward biased condition: A battery equal to cut-in voltage V_r and the forward resistance in series with the ideal diode.

(1) Reverse biased condition; I_0 is very small & neglected, diode is open circuited (11)

(2) IDEAL DIODE MODEL



(i) Forward biased



(ii) Reverse biased

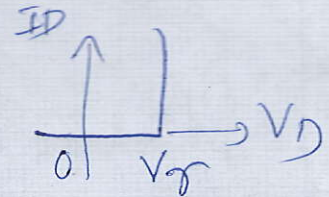
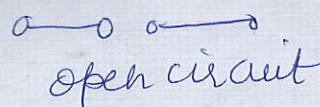
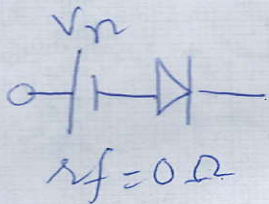


V-I characteristics

(i) Forward biased: Ideal diode starts conducting instantaneously when applied voltage V_D just greater than ~~V_D~~ zero and the drop across the conducting diode is zero. \therefore conducting diode is replaced by short circuit.

(ii) Reverse bias condition: $V_D < 0$, open circuited

(3) PIECEWISE LINEAR MODEL OF DIODE



(i) Forward biased (ii) Reverse biased

(i) Forward biased: $R_f = 0$. R_f is neglected & diode is assumed to conduct instantaneously when applied forward bias voltage V_D is equal to cut-in voltage V_r . The current increases instantaneously giving straight line.

(ii) Reverse biased: When $V_D < 0$, the diode does not conduct at all. Diode is open circuited

Applications of p-n diode

(12)

1. Rectifiers in power supplies
2. Clipper circuits used for wave shaping
3. Clamper circuits used as d.c restorer in T.V. receivers.
4. Voltage multipliers.
5. As a switch in digital circuits.